

UM10963

TEA1993DB1357 synchronous rectifier controller demo board Rev. 1 — 8 April 2016 User manual

Document information

Info	Content
Keywords	TEA1993DB1357, TEA1993TS, flyback converter, Synchronous Rectifier (SR) driver, TSOP-6, high efficiency, power supply, demo board
Abstract	This user manual describes the TEA1993DB1357 demo board. The TEA1993DB1357 demo board can be connected to a flyback converter.
	The TEA1993DB1357 demo board contains a TEA1993TS SR controller in a TSOP-6 package. Additionally, the TEA1993DB1357 demo board contains two possible options to place power MOSFETs. It replaces the secondary rectification part of the flyback converter.



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Revision history

Rev	Date	Description
v.1	20160408	first issue

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UM10963

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1. Introduction

WARNING

Lethal voltage and fire ignition hazard





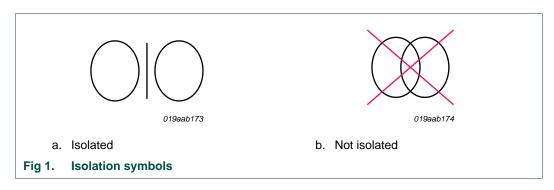
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This document describes the TEA1993DB1357 demo board. A functional description is provided, including instructions about how to connect the board, for the best results and performance. The TEA1993DB1357 demo board contains the secondary part of a single output flyback converter, excluding the output capacitors and the feedback control hardware. To use the TEA1993DB1357 demo board correctly, a flyback converter board in which the demo board can replace the secondary rectifier part is required.

2. Safety warning

The board application is AC mains voltage powered. Avoid touching the board while it is connected to the mains voltage and when it is in operation. An isolated housing is obligatory when used in uncontrolled, non-laboratory environments. Galvanic isolation from the mains phase using a fixed or variable transformer is always recommended. Figure 1 shows the symbols on how to recognize these devices.



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3. Board photographs

The TEA1993DB1357 demo board incorporates the TEA1993TS in TSOP-6 package and a MOSFET in LFPAK with a typical R_{DSon} of 4.8 $m\Omega.$ Figure 2 shows the front side and back side of the TEA1993DB1357 demo board. The TEA1993DB1357 demo board is a single layer board, which includes plated-through vias for external connections and the TO-220 MOSFET.



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a. Front side

Fig 2. TEA1993DB1357 demo board photographs

b. Back side

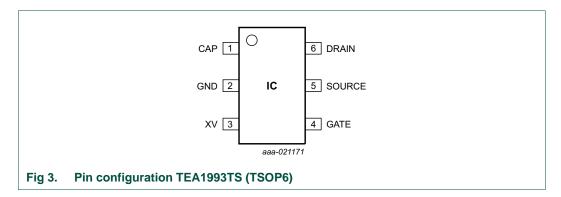
TEA1993DB1357 synchronous rectifier controller demo board

4. TEA1993TS SR controller

The TEA1993TS is a dedicated controller IC for synchronous rectification on the secondary side of flyback converters. It incorporates the sensing stage and driver stage for driving the SR MOSFET which rectifies the output of the secondary transformer winding.

The TEA1993TS can generate its own supply voltage or operate with an external applied voltage. The self-supply function is intended for:

- Battery charging applications with a 2 V (USB BC) output voltage
- · Applications with high-side rectification without an auxiliary winding
- multiple output voltage applications with or without auxiliary winding



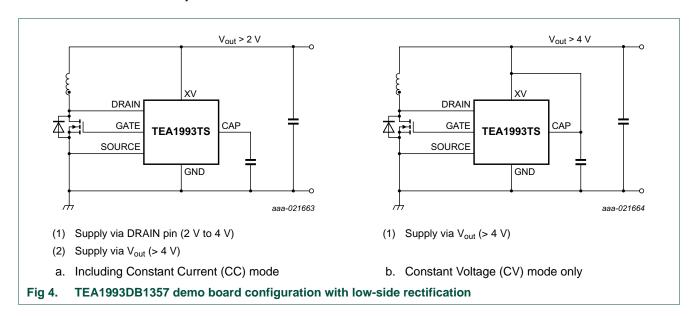
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5. TEA1993DB1357 demo board setup

5.1 Connected at low-side SR

The TEA1993DB1357 demo board is incorporated in an existing flyback power supply.

<u>Figure 4</u> shows the connection of the TEA1993DB1357 demo board to the secondary side of a flyback controller board as low-side SR.



<u>Figure 4</u>(a) shows the configuration for SR low-side applications that include CC mode (e.g. USB BC specification for an operation between 2 V and 5 V). When $V_{out} \ge 4.7$ V, the TEA1993TS uses the voltage on the XV pin as supply. The resulting voltage on the CAP pin is typically 0.7 V below the voltage on the XV pin. It is used as supply voltage for the gate drive output to the external MOSFET.

When V_{out} < 4.7 V (CC mode), the TEA1993TS uses the pulsed voltage on the drain input to generate the voltage for the CAP pin. When 0 V <V_{out} < 4.7 V, the regulated voltage on the CAP pin is 4.0 V (typical).

<u>Figure 4</u>(b) shows the configuration for SR low-side application for CV mode only. V_{out} must be ≥ 4 V. In this case, the CAP pin can be connected directly to the XV pin. The result of connecting the CAP pin directly to the XV pin is 0.7 V additional gate drive voltage compared to the configuration in <u>Figure 4</u>(a). The additional gate drive voltage drives the external MOSFET to a lower R_{DSon} to achieve the best efficiency. The maximum gate drive voltage is limited to 12 V.

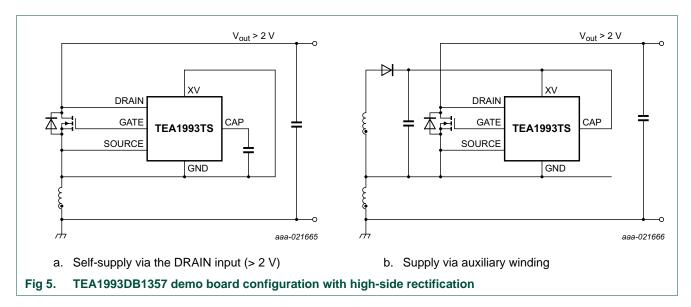
Maximum voltage ratings for TEA1993TS pins:

Pins XV and CAP: 38 VPin DRAIN: 120 V

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5.2 Connected at high-side SR

<u>Figure 5</u> shows the connection of the TEA1993DB1357 demo board to the secondary side of a flyback controller board as high-side SR.



<u>Figure 5(a)</u> shows the configuration for SR high-side applications with self-supply. In this case, the TEA1993TS retrieves its supply from the pulsed voltage on the DRAIN input. The regulator inside the TEA1993TS converts these pulses to an approximately 9 V regulated DC voltage. If the XV pin is connected to the IC ground, the TEA1993TS generates 9 V. This voltage is present on the CAP pin. It is the reference voltage for the gate drive of the external MOSFET.

<u>Figure 5(b)</u> shows the configuration for SR high-side application which is supplied by an additional auxiliary winding. This configuration can deliver the best possible efficiency for high-side application.

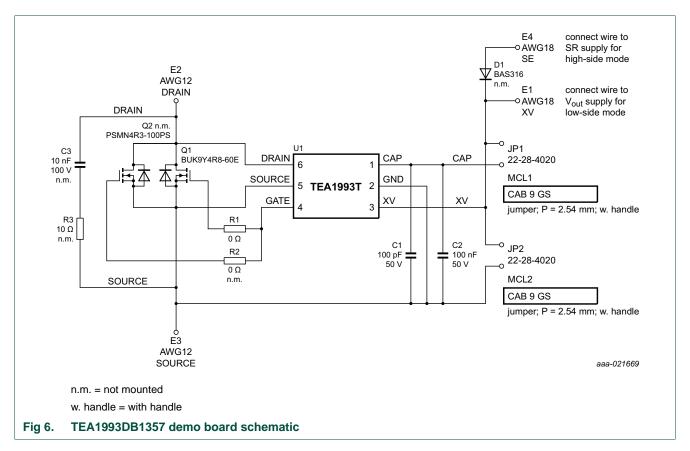
If, in a multiple-outputs application, the auxiliary voltage drops below the 4 V for the lower output voltages, the TEA1993TS generates its own supply voltage. It maintains a minimum supply of 4 V on the CAP pin. The auxiliary voltage can then be optimized for the higher output voltages. In this way, maximum efficiency at maximum power is achieved.

Maximum voltage ratings for TEA1993TS pins:

Pins XV and CAP: 38 VPin DRAIN: 120 V

TEA1993DB1357 synchronous rectifier controller demo board

6. Schematic



<u>Figure 6</u> shows the schematic diagram of the TEA1993DB1357 demo board. The board incorporates the TEA1993TS SR controller and a power MOSFET. The TEA1993TS acts as a controlled amplifier. The input is the voltage difference between the DRAIN and the SOURCE pin. The corresponding gate driver signal is the output. The amplifier regulates the source-to-drain voltage difference to 35 mV in the rectification phase.

To facilitate easy layout design for a single-sided board, resistors R1 and R2 are added. They must be between 0 Ω and 10 Ω . For the fastest turn-off time, use the lowest value. By default, the LFPAK MOSFET Q1 is mounted with a 0 Ω gate resistor (R1). It is also possible to mount a TO220 MOSFET Q2 with gate resistor R2. Capacitors C1 and C2 are decoupling capacitors for the V_{CC} of the TEA1993TS. Connect these capacitors close to the IC.

To ensure sufficient charge power during the secondary stroke to drive the external MOSFET, a value of 100 nF is used for capacitor C2. To prevent unwanted oscillation of the V_{CC} supply, capacitor C1 is added. A provision is made for snubber R3/C3. The components are not mounted. However, if high-voltage spikes occur on the drain-source connections of the MOSFETs, they can be added. To facilitate optimal configurations for either the low-side or the high-side connection, jumpers JP1 and JP2 are added (see the diagrams in Section 5).

TEA1993DB1357 synchronous rectifier controller demo board

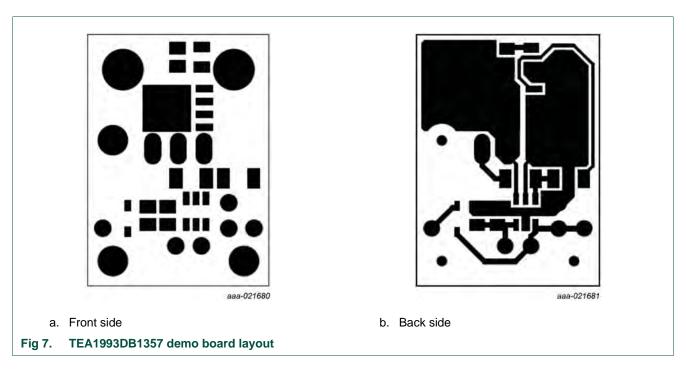
7. Bill Of Materials (BOM)

Table 1. TEA1993DB1357 demo board BOM

Reference	Description and values	Part number	Manufacturer
C1; C2	capacitor; 100 pF; 50 V; 0805	-	-
C3	capacitor; not mounted; 10 nF; 100 V;		-
D1	diode; not mounted; SOD323	BAS316	NXP Semiconductors
JP1; JP2	header; straight; 1 × 2-way	22-28-4020	Molex
MCL1; MCL2	jumper; with handle; P = 2.54 mm	CAB 9 GS	Fischer
R1	resistor; 0 Ω; 1206	-	-
R2	resistor; not mounted; 0 Ω; 1206	-	-
R3	resistor; not mounted; 10 Ω; 0805	-	-
Q1	MOSFET; LFPAK	BUK9Y4R8-60E	NXP Semiconductors
U1	SR controller; TEA1993TS	TSOP-6	NXP Semiconductors

TEA1993DB1357 synchronous rectifier controller demo board

8. Layout



Some important guidelines for a good layout:

- Keep the trace from the DRAIN pin to the MOSFET drain as short as possible
- Keep the trace from the SOURCE pin to the MOSFET source as short as possible
- Keep the area of the loop from the DRAIN pin, to the MOSFET drain, to the MOSFET source, and to the SOURCE pin as small as possible. Make sure that the overlap of this loop over the power drain track or the power source track is as small as possible. Take care that the two loops do not cross each other.
- Keep the track from the GATE pin to the gate of the MOSFET as short as possible
- Use separate clean tracks for the XV and the GND pins. If possible, use a small ground plane underneath the IC, which improves the heat dispersion.

TEA1993DB1357 synchronous rectifier controller demo board

9. NXP Semiconductors power MOSFETs

Table 2. Extract from the NXP Semiconductors power MOSFET selection guide

Type number	Package name	V _{DS(max)} (V)	$R_{DSon(max)}$ at $V_{GS} = 10 \text{ V}$ (m Ω)	I _{D(max)} (A)	Q _{GD} (typical; nC)	Q _{G(tot)} (typical; nC)
PSMN2R4-30MLD	LFPAK33	30	2.4	70	5.6	16
PSMN1R0-30YLD	LFPAK56	30	1.02	100	11	38
PSMN1R0-40YLD	LFPAK56	40	1.1	100	17	59
PSMN1R4-40YLD	LFPAK56	40	1.4	100	13	45
PSMN1R5-40ES	I2PAK	40	1.6	120	32	136
PSMN1R5-40PS	TO-220AB	40	1.6	150	32	136
PSMN1R6-40YLC	LFPAK56	40	1.55	100	15.3	59
PSMN1R8-40YLC	LFPAK56	40	1.8	100	10.9	45
PSMN1R9-40PL	TO-220AB	40	1.7	150	40.9	230
PSMN2R1-40PL	TO-220AB	40	2.2	150	29.6	168.9
PSMN2R2-40PS	TO-220AB	40	2.1	100	25	110
PSMN2R6-40YS	LFPAK56	40	2.8	100	14	63
PSMN2R8-40PS	TO-220AB	40	2.8	100	17	71
PSMN3R3-40YS	LFPAK56	40	3.3	100	11.2	49
PSMN4R0-40YS	LFPAK56	40	4.2	100	7	38
PSMN4R5-40PS	TO-220AB	40	4.6	100	8.8	35
PSMN5R8-40YS	LFPAK56	40	5.7	90	7.8	28.8
PSMN8R0-40PS	TO-220AB	40	7.6	77	3.8	17
PSMN8R3-40YS	LFPAK56	40	8.6	70	4.5	20
PSMN2R0-60ES	I2PAK	60	2.2	120	32	137
PSMN2R0-60PS	TO-220AB	60	2.2	120	32	137
PSMN2R5-60PL	TO-220AB	60	2.6	150	41.2	223
PSMN2R6-60PS	TO-220AB	60	2.6	150	43.7	140
PSMN3R0-60ES	I2PAK	60	3	100	28	130
PSMN3R0-60PS	TO-220AB	60	3	100	28	130
PSMN3R3-60PL	TO-220AB	60	3.4	130	31	175
PSMN3R9-60PS	TO-220AB	60	3.9	130	33	103
PSMN4R2-60PL	TO-220AB	60	3.9	130	27	151
PSMN4R6-60PS	TO-220AB	60	4.6	100	14.8	70.8
PSMN5R5-60YS	LFPAK56	60	5.2	100	11.2	56
PSMN7R0-60YS	LFPAK56	60	6.4	89	9.6	45
PSMN7R6-60PS	TO-220AB	60	7.8	92	10.6	38.7
PSMN8R5-60YS	LFPAK56	60	8	76	7.7	39
PSMN3R3-80ES	I2PAK	60	3.3	120	27	139
PSMN3R3-80PS	TO-220AB	60	3.3	120	27	139
PSMN3R5-80ES	I2PAK	80	3.5	120	27	139
PSMN3R5-80PS	TO-220AB	80	3.5	120	27	139

TEA1993DB1357 synchronous rectifier controller demo board

Table 2. Extract from the NXP Semiconductors power MOSFET selection guide ...continued

Type number	Package name	V _{DS(max)} (V)	$R_{DSon(max)}$ at $V_{GS} = 10 \text{ V}$ (m Ω)	I _{D(max)} (A)	Q _{GD} (typical; nC)	Q _{G(tot)} (typical; nC)
PSMN4R3-80ES	I2PAK	80	4.3	120	28	111
PSMN4R3-80PS	TO-220AB	80	4.3	120	28.4	111
PSMN4R4-80PS	TO-220AB	80	4.1	100	25	112
PSMN5R0-80PS	TO-220AB	80	4.7	100	21	87
PSMN6R5-80PS	TO-220AB	80	6.9	100	16	71
PSMN8R2-80YS	LFPAK56	80	8.5	82	12	55
PSMN8R7-80PS	TO-220AB	80	8.7	90	11	52
PSMN4R3-100ES	I2PAK	100	4.3	120	49	170
PSMN4R3-100PS	TO-220AB	100	4.3	120	49	170
PSMN5R0-100ES	I2PAK	100	5	120	49	170
PSMN5R0-100PS	TO-220AB	100	5	120	49	170
PSMN5R6-100PS	TO-220AB	100	5.6	100	43	141
PSMN7R0-100ES	I2PAK	100	6.8	100	36	125
PSMN7R0-100PS	TO-220AB	100	6.8	100	36	125
PSMN8R5-100ES	I2PAK	100	8.5	100	33	111
PSMN8R5-100PS	TO-220AB	100	8.5	100	33	111
PSMN6R3-120ES	I2PAK	120	6.7	70	61.9	207.1
PSMN6R3-120PS	TO-220AB	120	6.7	70	61.9	207.1
PSMN7R8-120ES	I2PAK	120	7.9	70	50.5	167
PSMN7R8-120PS	TO-220AB	120	7.9	70	50.5	167

TEA1993DB1357 synchronous rectifier controller demo board

10. Abbreviations

Table 3. Abbreviations

Acronym	Description		
SR	ynchronous Rectifier		
MOSFET	Metal-Oxide-Semiconductor Field-Effect Transistor		
CC	Constant Current		
CV	Constant Voltage		

11. References

[1] **TEA1993TS data sheet** — GreenChip synchronous rectifier controller; 2015, NXP Semiconductors

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